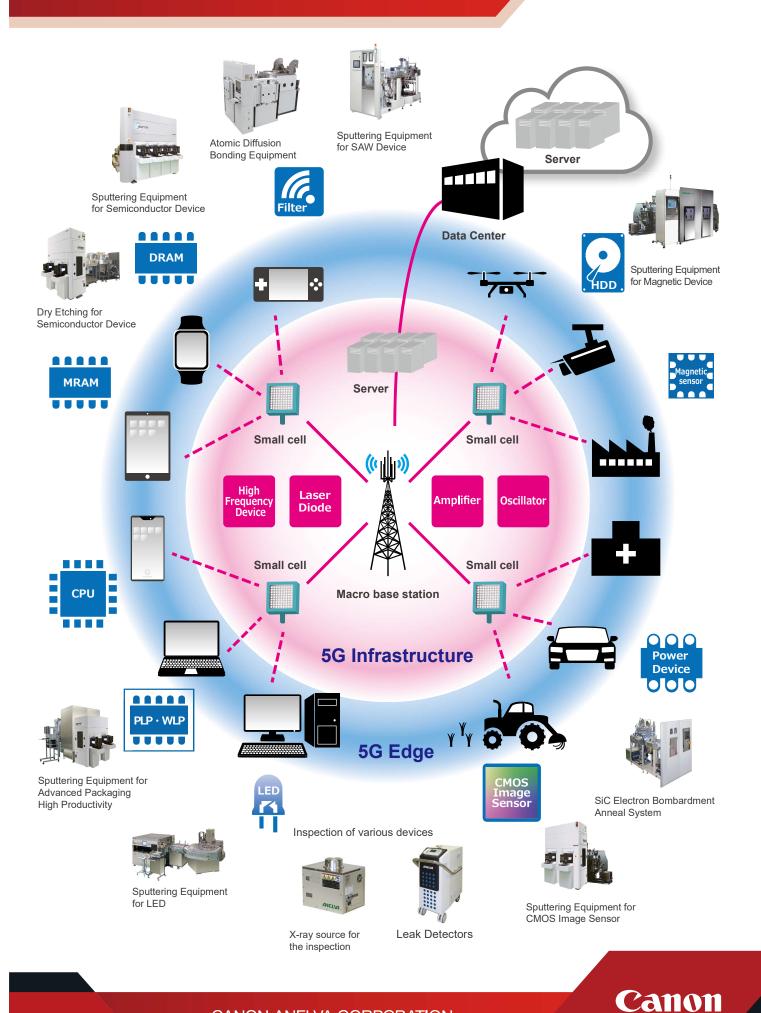
Contribution for various 5G device manufacturing



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Semiconductor Device Manufacturing Equipment

MRAM Sputtering Equipment NC7900

- ✓ Fine interface control with ultra thin multi layers
- ✓ Compatible with Planar & Perpendicular MTJ formation

Application : MRAM deposition

MRAM Dry Etching Equipment NC8000

- ✓ Micropattern processing free of damage
- ✓ Capable of retaining a high MR ratio even after etching
- ✓ Protective CVD film formation after etching process

Application: MRAM etching

Interconnect Sputtering Equipment IC7500

- ✓ Cathode magnet position (3D) is variable in-situ per each recipe
- ✓ Optional cathode of PCM (Point Cusp Magnet) improves step coverage and suppresses plasma damage

Application: Interconnect metal process

Ultra Thin film Sputtering Equipment FC7100

- ✓ Damage-less metal gate production
- ✓ Precise composition control by co-sputtering
- \checkmark Ultra thin (0.1nm unit) and excellent uniformity $(1\sigma < 1\%)$ film deposition process

Application : Metal Gate Transistor CMOS Imaging sensor, ReRAM



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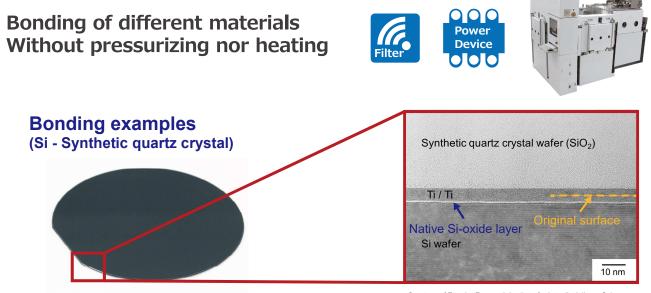


MRAM

Electronic Device Manufacturing Equipment

Creating the innovative device with new performance, structure and process

Atomic Diffusion Bonding Equipment BC7000



Courtesy of Frontier Research Institute for Interdisciplinary Sciences, Tohoku University, Shimatsu Labo.

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Improvement of thermal conductivity at bonding interface \sim High power device for 5G communication \sim

GaN HEMT DHBT (Double Heterojunction Bipolar Transistors) Gate SiC Substrate Source Drain SiC Substrate Fmitter AlGaN Base SiC Substrate Collector Bonding GaN Epi. Laver Epi. Layer Bondina SiC Substrate InP Substrate InP Substrate Peeling InP Substrate SiC Substrate Enhancement of thermal conductivity Enhancement of thermal conductivity by the bonding of different materials by layer transcription Improvement of electric conductivity Improvement of light transmittance rate at bonding interface at bonding interface \sim 3D Packaging \sim \sim Ultra low loss output \sim **Optical Device** CMOS-Image sensor, Memory Quartz Quartz 22222222 Glue Bonding Bondina Micro Bump Quartz Quartz Improvement of electric conductivity without bump No thermal damage

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